AMENDMENTS TO THE CLAIMS

Please enter the following amendments:

1. (Currently Amended) A non-volatile semiconductor recording medium comprising:

a partition management information region;

a partition region; and

a switch region located between a terminal end of the partition management information region and a starting end of the partition region, wherein

each of the partition management information region and the partition region is allocated to at least one memory block, each memory block being physically erasable as a single unit, [[and]]

the switch region is allocated to at least 200 memory blocks and is in a state where data is physically erased, and

the switch region cannot be accessed by a file system that manages inside the partition region.

2. (Previously Presented) A non-volatile semiconductor recording medium comprising:

a partition management information region;

a first partition region; and

a second partition region located after the first partition region; wherein

a single address space includes a first address value corresponding to the beginning of the first partition region, a second address value corresponding to the terminal end of the first partition region, and a third address value corresponding to the beginning of the second partition region;

the first and third address values are recorded in the partition management information region;

the second and third address values are not consecutive, and are separated by at least three consecutive address values corresponding to a switch region located between the first and second partition regions; and

the switch region is physically erased.

3. (Canceled)

4. (Previously Presented) A non-volatile semiconductor recording medium comprising:

a partition management information region;

and a partition containing a FAT file system; wherein

an information on a start position of the partition is recorded in the partition management information region;

the partition comprises a partition boot information region and a file allocation table region;

an information on a plural number of reserved sectors, the reserved sectors being positioned in the partition between the partition boot information region and a starting end of the file allocation table region, is recorded in the partition boot information region; and

the region secured between the terminal end of the partition boot information region and the starting end of the file allocation table region is in a state where data is physically erased.

5 – 6. (Canceled)

7. (Currently Amended) A method of recording information in a non-volatile semiconductor recording medium, said recording medium comprising a partition management

information region, a partition region, and a switch region located between a terminal end of the

partition management information region and a starting end of the partition region, wherein

each of the partition management information region and the partition region is allocated

to at least one memory block, each memory block being physically erasable as a single unit;

[[and]]

the switch region is allocated to at least 200 memory blocks and is in a state where data is

physically erased, and

the switch region cannot be accessed by a file system that manages inside the partition

region.

8. (Previously Presented) A method of recording information in a non-volatile

semiconductor recording medium, wherein

a partition management information region, a first partition region, and a second partition

region located after the first partition region are set in the recording medium;

a single address space includes a first address value corresponding to the beginning of the

first partition region, a second address value corresponding to the terminal end of the first

partition region, and a third address value corresponding to the beginning of the second partition

region;

the first and third address values are recorded in the partition management information

region;

the second and third address values are not consecutive, and are separated by at least

three consecutive address values corresponding to a switch region located between the first and

second partition regions; and

the switch region is physically erased.

9. (Canceled)

10. (Previously Presented) A method of recording information in a non-volatile semiconductor recording medium, wherein

a partition management information region and a partition containing a FAT file system are set in the recording medium;

an information on a start position of the partition is recorded in the partition management information region;

the partition comprises a partition boot information region and a file allocation table region,

an information on a plural number of reserved sectors, the reserved sectors being positioned in the partition between the partition boot information region and a starting end of the file allocation table region, is recorded in the partition boot information region, and

the region secured between the terminal end of the partition boot information region and the starting end of the file allocation table region is in a state where data is physically erased.

11 – 12. (Canceled)

13. (Currently Amended) An information recording format for a non-volatile semiconductor recording medium, said recording medium comprising a partition management information region, a partition region, and a switch region located between a terminal end of the partition management information region and a starting end of the partition region, wherein

each of the partition management information region and the partition region is allocated to at least one memory block, each memory block being physically erasable as a single unit;

[[and]]

the switch region is allocated to at least 200 memory blocks and is in a state where data is physically erased, and

the switch region cannot be accessed by a file system that manages inside the partition region.

14. (Previously Presented) An information recording format for a non-volatile semiconductor recording medium, wherein

a partition management information region, a first partition region, and a second partition region located after the first partition region are set in the recording medium;

a single address space includes a first address value corresponding to the beginning of the first partition region, a second address value corresponding to the terminal end of the first partition region, and a third address value corresponding to the beginning of the second partition region;

the first and third address values are recorded in the partition management information region;

the second and third address values are not consecutive, and are separated by at least three consecutive address values corresponding to a switch region located between the first and second partition regions; and

the switch region is physically erased.

15. (Canceled)

16. (Previously Presented) An information recording format for a non-volatile semiconductor recording medium, wherein

a partition management information region and a partition containing a FAT file system are set in the recording medium;

an information on a start position of the partition is recorded in the partition management

information region;

the partition comprises a partition boot information region and a file allocation table

region;

an information on a plural number of reserved sectors, the reserved sectors being

positioned in the partition between the partition boot information region and a starting end of the

file allocation table region, is recorded in the partition boot information region; and

the region secured between the terminal end of the partition boot information region and

the starting end of the file allocation table region is in a state where data is physically erased.

17 – 18. (Canceled)